# MOCVD Reactors

Taiyo Nippon Sanso Corporation (TNSC) was the first in the world to develop MOCVD equipment to produce compound semiconductors utilized in LEDs, lasers, and high performance electronics for applications such as mobile phones, advanced lighting, and optical communications systems.







TNSC equipment is highly regarded worldwide for its exceptionally stable performance.

### FR Series Reactors for Research and Small Scale Production

 $Ga_2O_3$  and related alloy processing for wafers up to 50 mm

#### **UR Series Reactors for Mass Production**

GaN and related alloy processing for wafer diameters up to 200 mm

#### **SR Series** Reactors for Research and Small Scale Production

GaN and related alloy processing for wafer diameters up to 150 mm

#### HR Series Reactors for Research and Mass Production

GaAs, InP, and related alloy processing for wafer diameters up to 200 mm

## **BRC/BMC Series** Reactors for Research and Mass Production

GaAs, InP, and related alloy processing for wafer diameters up to 150 mm

TNSC, along with its sister companies, MATHESON (U.S.) and Nippon Gases (Europe), offers complete end-to-end solutions for MOCVD customers:

- Arsine (AsH<sub>3</sub>), Phosphine (PH<sub>3</sub>), Silane (SiH<sub>4</sub>), and Ammonia (NH<sub>3</sub>) and other primary gases that are used in MOCVD applications.
- Ultrapurification equipment for integration with MOCVD equipment for highest quality processing.
- Gas handling equipment and abatement solutions for safe and reliable MOCVD operations.

Contact us for more information at <a href="mailto:info@tnsc-innovation.com">info@tnsc-innovation.com</a>.



